ABSTRACT

A system of Flash EEprom memory chips with controlling circuits serves as non-volatile memory such as that provided by magnetic disk drives. Improvements include selective multiple sector erase, in which any combinations of Flash sectors may be erased together. Selective sectors among the selected combination may also be de-selected during the erase operation. improvement is the ability to remap and defective cells with substitute cells. The remapping is performed automatically as soon as a defective cell is When the number of defects in a Flash sector becomes large, the whole sector is remapped. another improvement is the use of a write cache to reduce the number of writes to the Flash EEprom memory, thereby minimizing the stress to the device undergoing too many write/erase cycling.